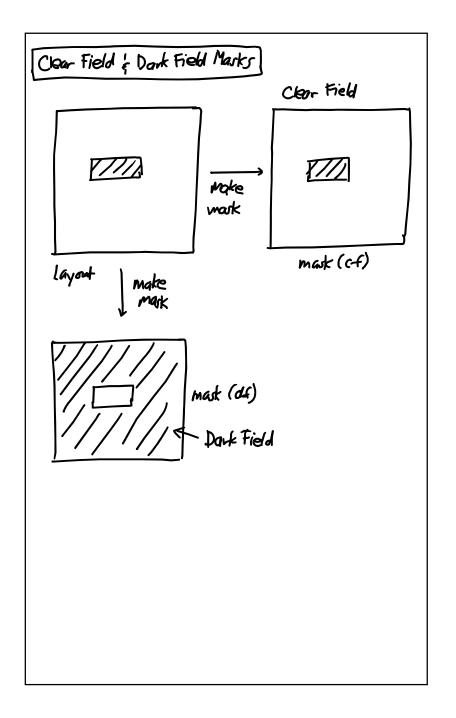
<u>EE C247B/ME C218</u>: Introduction to MEMS Design Lecture 7w: Surface Micromachining I

Lecture 7: Surface Micromachining I Announcements: · HW#2 due Thursday, 2/21 at 9 a.m. Surface Micromachining Module 5 & Handouts online Today: Senturia, Chpt. 3; Jaeger, Chpt. 2, 3, 6 · Lecture Topics: **SExample MEMS fabrication processes** Photolithography **Setching Oxidation ♥ Diffusion ♦** Ion Implantation Reading: Senturia Chpt. 3, Jaeger Chpt. 11, Handouts: "Surface Micromachining for Microelectromechanical Systems", "Etch Rates for Micromachining—Part II" · Lecture Topics: \$ Polysilicon surface micromachining **♦** Stiction ♥ Residual stress ♦ Topography issues Solickel metal surface micromachining \$3D "pop-up" MEMS \$ Foundry MEMS: the "MUMPS" process ♦ The Sandia SUMMIT process · Last Time: Diffusion section of Module 4



Straight or Sloped Sidewalls: Often want sloped sidewalls in order to reduce the sharpness of corners \$ Easier to deposit over \$ Sharp corners concentrate stresses \$ High stress can weaken structures creating a reliabilty concern \$High stress can dissipate energy, lowering Q · When you want straight sidewalls (e.g., for lateral electrostatic drive), use a hard mask ♦ PR can't last for thick structures ♦ A hard mask suppresses angle transfer Elching Slopod or Straight Sidewalls Assume: perfectly anisotropic etch straight sidewalls - SiO, terult: stronget stocalls Substab

